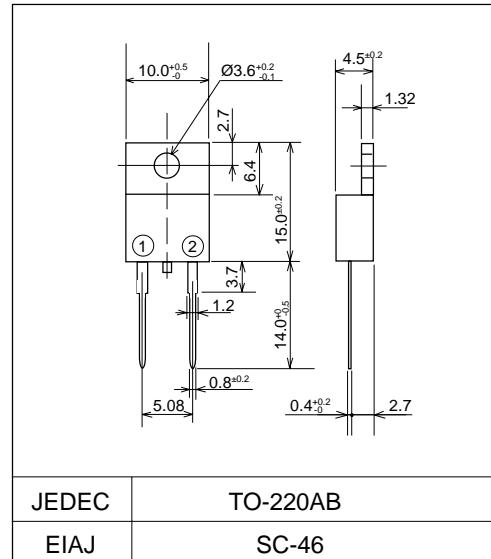


## SCHOTTKY BARRIER DIODE

## ■ Outline drawings, mm



## ■ Features

- Low VF
- Super high speed switching
- High reliability by planer design

## ■ Applications

- High speed power switching

## ■ Maximum ratings and characteristics

- Absolute maximum ratings

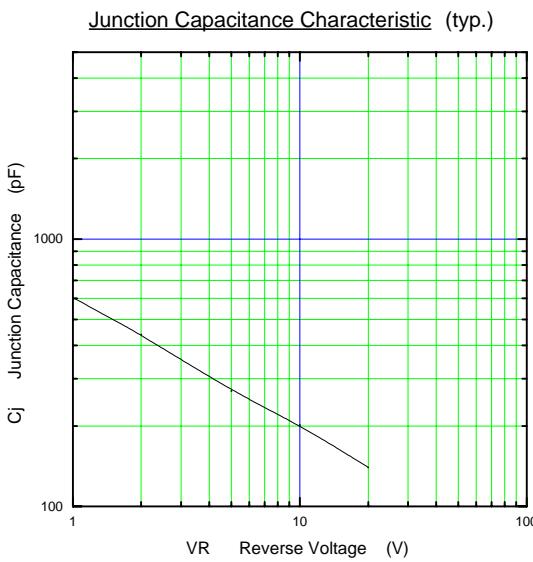
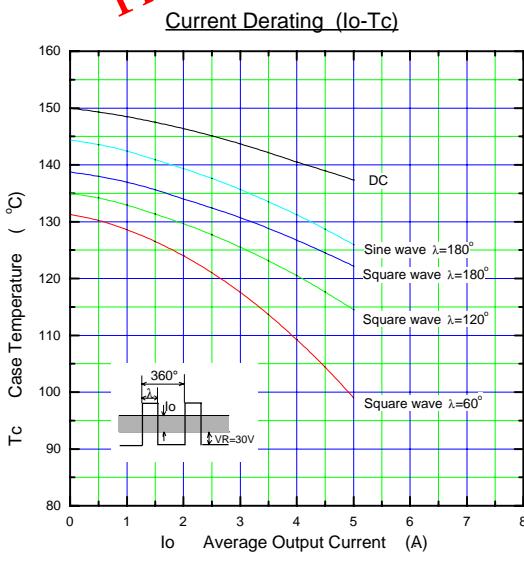
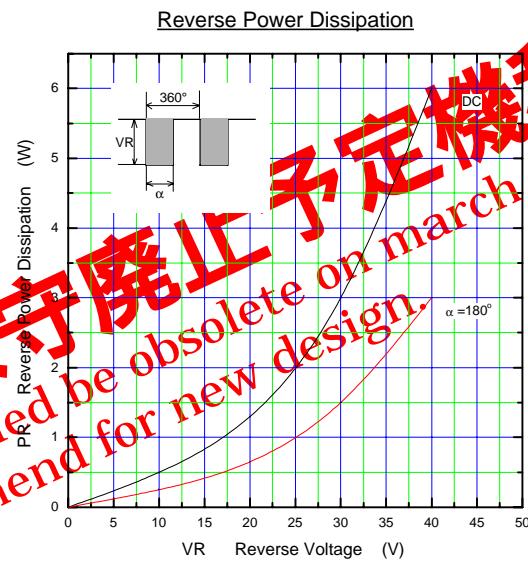
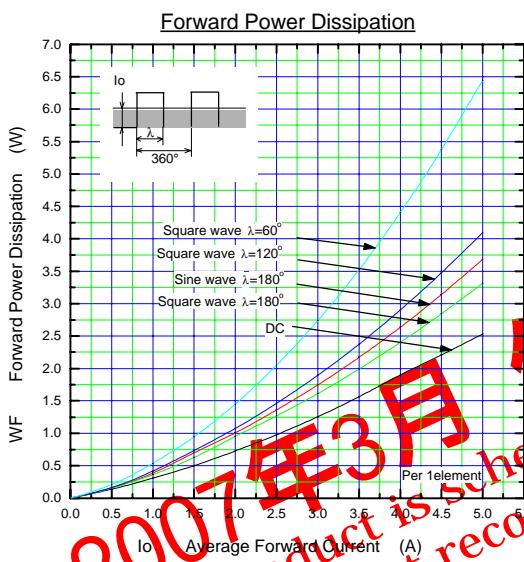
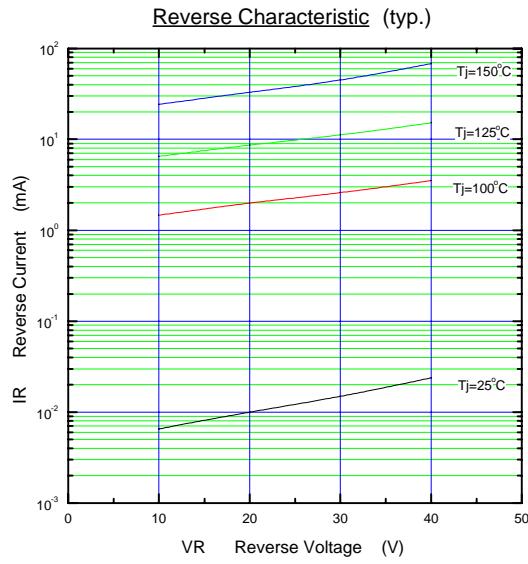
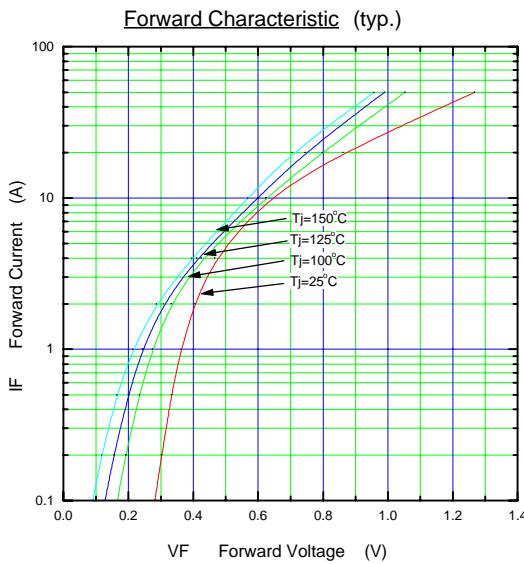
Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V <sub>RRM</sub>		40	V
Non-repetitive peak reverse voltage	V <sub>RSM</sub>	t <sub>w</sub> =500ns, duty=1/40	48	V
Average output current	I <sub>o</sub>	Square wave, duty=1/2 T <sub>c</sub> =122°C	5.0	A
Surge current	I <sub>FSM</sub>	Sine wave 10ms	120	A
Operating junction temperature	T <sub>j</sub>		-40 to +150	°C
Storage temperature	T <sub>stg</sub>		-40 to +150	°C

- Electrical characteristics (Ta=25°C Unless otherwise specified )

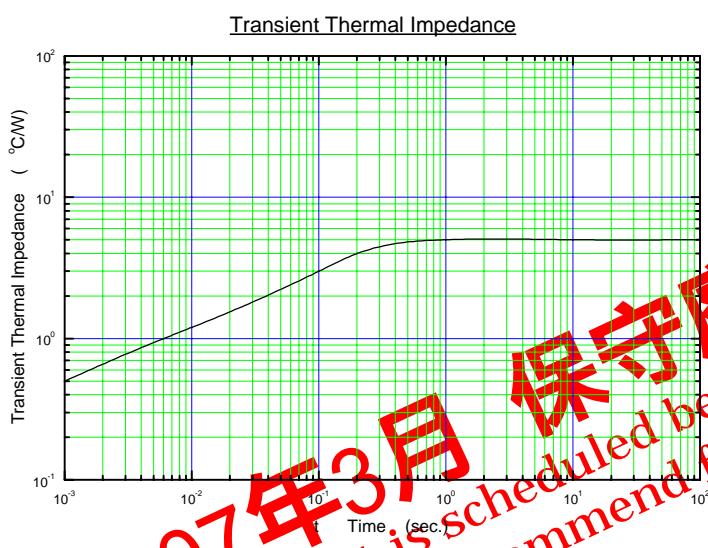
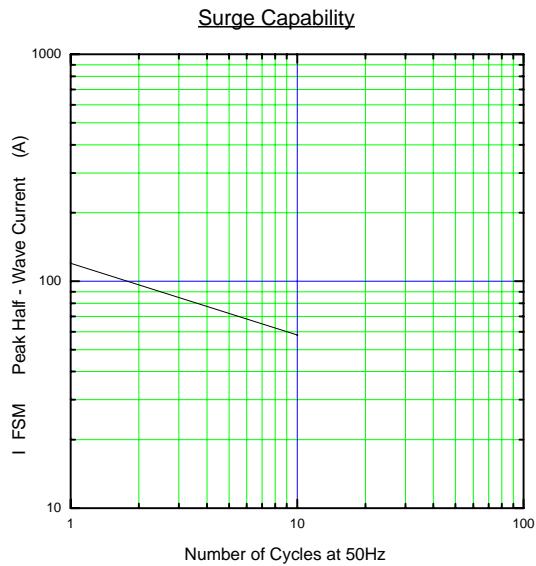
Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V <sub>FM</sub>	I <sub>FM</sub> =5.0A	0.55	V
Reverse current	I <sub>RRM</sub>	V <sub>R</sub> =V <sub>RRM</sub>	5.0	mA
Thermal resistance	R <sub>th(j-c)</sub>	Junction to case	5.0	°C/W

2007年3月保守廢止予定機種  
This product is scheduled to be obsolete on March 2007.  
Not recommend for new design.

## ■ Characteristics



$\lambda$ : Conduction angle of forward current for each rectifier element  
Io: Output current of center-tap full wave connection



2007年3月 保守停止予定機種  
This product is scheduled to be obsolete on March 2007.  
Not recommended for new design.